NSN 5961-01-309-8672

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View Online at https://aerobasegroup.com/nsn/5961-01-309-8672 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** 0.300 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204aa **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 250.0 drain to source voltage and 250.0 drain to gate voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 10.00 amperes drain current and 30.00 amperes off-state current, peak **Power Rating Per Characteristic:** 100.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: